

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

2SK632

FEATURES

- Drain Current $-I_D$ =5A@ T_C =25°C
- Drain Source Voltage-
 - : V_{DSS}= 200V(Min)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

8

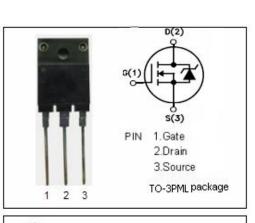
• Designed for high voltage, high speed power switching applications such as switching regulators, converters, solenoid and relay drivers.

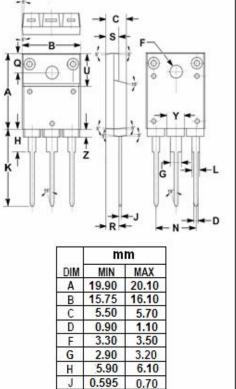
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
ID	Drain Current-Continuous	5	А
PD	Total Dissipation @T _C =25°C	40	W
TJ	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature		°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.12	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W





21.10

1.90

4.90

3.75

3.20

4.20

10.80 11.00

9.90 10.10

22.50

2.25

5.10

3.95

3.60

4.90

2.10

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	200			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 1mA	1.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 15V; I _D = 3A			1.2	Ω
lgss	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =160V; V _{GS} =0			1	μA

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